

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	S15 and ((implant\$4 and (dual double second two)	USPAT	OR	OFF	2005/06/07 11:21
L2	0	krishnaswamy-ramkumar.in.	USPAT	OR	OFF	2005/06/07 11:23
L3	1	("krishnaswamy-ramkumar.in.").PN.	USPAT; USOCR	OR	OFF	2005/06/07 11:23
L4	36	krishnaswamy-ramkumar.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/07 11:24
L5	5	ramkumar-krishnaswamy.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/07 11:33
L6	29	bamgolker-hanna.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/07 11:33
L7	1480	("3430109" "3585714" "4256514" "4639288" "4851361" "4916513" "4946800" "4965221" "4992390" "5151381" "5296094" "5334861" "5393679" "5431778" "5443998" "5447884" "5498577" "5672521" "5679483" "5688701" "5702988" "5739056" "5750428" "5792680" "5795803" "5869385" "5900658").PN. OR ("6555484").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/07 12:35
L8	137	(438/229,514,519,522,911,920, 981).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/07 12:42
L9	86	L7 and ((screen\$3 sacrificial) with oxid\$5)	USPAT	OR	OFF	2005/06/07 12:43
L10	11	L8 and ((implant\$5 dop\$3) with (dual double two twice second))	USPAT	OR	OFF	2005/06/07 12:43
L11	97959	L9 and (anneal with (dual double twice second two))	USPAT	OR	OFF	2005/06/07 12:43
L12	3134	("438").CLAS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/07 12:42
L13	1609	L11 and ((screen\$3 sacrificial) with oxid\$5)	USPAT	OR	OFF	2005/06/07 12:43
		L12 and ((implant\$5 dop\$3) with (dual double two twice second))	USPAT	OR	OFF	2005/06/07 12:43

L14	101	L13 and (anneal with (dual double twice second two))	USPAT	OR	OFF	2005/06/07 12:46
L15	100	L14 and silicon	USPAT	OR	OFF	2005/06/07 12:47
L16	42	L15 and "silicon oxide"	USPAT	OR	OFF	2005/06/07 12:47
S1	307230	EEPROM EPROM ROM "read only memory" flash non-volatile	USPAT	OR	OFF	2005/05/26 14:56
S2	49796	S1 and (implant\$5 impurity ion dop\$3)	USPAT	OR	OFF	2005/05/26 14:57
S3	18059	S2 and (anneal thermal RTA drive-in)	USPAT	OR	OFF	2005/05/26 14:58
S5	5220	S3 and (tunnel 100A floating F-N fowler-nordheim)	USPAT	OR	OFF	2005/05/26 15:07
S8	1556	S5 and ((multiple with layers) (multiple with dielectric) (multiple with oxide) (plurality with layers) (plurality with dielectric) (plurality with oxide))	USPAT	OR	OFF	2005/05/26 15:10
S9	1460	S8 and silicon	USPAT	OR	OFF	2005/05/26 15:24
S10	115	(438/529 438/530) and (EEPROM EPROM flash floating non-volatile)	USPAT	OR	OFF	2005/05/26 15:45
S11	124	(438/529 438/530) and (EEPROM EPROM flash floating non-volatile tunnel)	USPAT	OR	OFF	2005/05/26 17:14
S12	0	438/257,263,264	USPAT	OR	OFF	2005/05/26 17:16
S13	355	438/257-267	USPAT	OR	OFF	2005/05/26 17:16
S14	25	438/257-264	USPAT	OR	OFF	2005/05/26 17:17
S15	2728	(438/257-264).CCLS.	USPAT; USOCR	OR	OFF	2005/05/26 17:17
S16	1873	S15 and (implant\$4 and (dual double second two))	USPAT	OR	OFF	2005/05/26 17:43
S17	264	S16 and (anneal and (dual double twice two second))	USPAT	OR	OFF	2005/05/26 17:44
S18	463	(438/529-530).CCLS.	USPAT; USOCR	OR	OFF	2005/05/26 17:19
S19	0	("L7and(EEPROM EPROM flash floatin gnon-volatiletunnel)").PN.	USPAT; USOCR	OR	OFF	2005/05/26 17:19
S20	72	S18 and (EEPROM EPROM flash floating non-volatile tunnel)	USPAT	OR	OFF	2005/05/26 17:20
S21	832	S15 and (implant\$4 with (dual double second two))	USPAT	OR	OFF	2005/05/26 17:43
S22	22	S21 and (anneal with (dual double twice two second))	USPAT	OR	OFF	2005/05/26 17:43
S24	223	S17 and (silicon with oxide)	USPAT	OR	OFF	2005/05/26 17:44
S25	3275	(257/314-326).CCLS.	USPAT; USOCR	OR	OFF	2005/06/02 15:44

S26	4289	(257/314-326).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/02 15:44
S27	0	("L2and(implant\$5same(dualdouble secondtwo)))".PN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/02 15:45
S28	1945	S26 and (implant\$5 same (dual double second two))	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/02 15:45
S29	360	S28 and (anneal\$3 same (dual double twice two second))	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/02 15:46
S30	986	S28 and (tunnel same (oxid\$5)) and silicon	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/02 15:47
S31	168	S29 and (tunnel same (oxid\$5)) and silicon	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 11:43
S32	209	(438/914,923).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 11:44
S33	9	S32 and (anneal with (dual double twice two second))	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 12:02
S34	0	chang-hun-han.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 12:04
S35	32	sakamoto-masaru.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 15:31
S36	0	dong-oog-kim.IN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 12:04
S37	378	(438/546).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 15:37

S38	369	(438/530).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 15:34
S39	3	S37 and S38	USPAT	OR	OFF	2005/06/03 15:34
S40	3	S37 and (anneal with (dual double twice two second))	USPAT	OR	OFF	2005/06/03 15:35
S41	3	S37 and (anneal with (dual double twice two second))	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 15:36
S42	154	S37 and silicon	USPAT	OR	OFF	2005/06/03 15:37
S43	4	S42 and ((screen\$3 sacrificial) near5 (oxid\$5))	USPAT	OR	OFF	2005/06/03 15:40
S44	744	(438/530,546).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 15:41
S45	1630	(438/530,546,550,766,770).CCLS.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 15:41
S46	0	("L9andsiliconwithoxide").PN.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2005/06/03 15:42
S47	882	S45 and silicon with oxide	USPAT	OR	OFF	2005/06/03 15:42
S48	93	S47 and ((screen\$3 sacrificial) near5 oxid\$5)	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2005/06/03 15:43